Preliminary communication

The conformations of six-membered indium-arsenic and gallium-antimony rings *

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Abstract

An X-ray diffraction study reveals that the solid state of $[Me_2InAsMe_2]_3$ contains two independent molecules per asymmetric unit: one has a planar In_3As_3 ring while the other is puckered. The Ga₃Sb₃ ring of $[Cl_2GaSb(t-Bu)_2]_3$ (2) is basically boat-shaped, with one Sb atom and one Ga atom 0.938 Å and 0.620 Å respectively above the central Ga₂Sb₂ plane of the molecule.

There is a rapidly growing interest in the chemistry of compounds containing bonds between the heavier group 13 and 15 elements. One reason for this is their potential as useful precursors to semiconductors such as GaAs and InP [1]. Pioneering work by Beachley and Coates [2] demonstrated that compounds of the general type $[Me_2MEMe_2]_{\star}$ (M = Al, Ga, In; E = P, As) can be prepared by the thermal reaction of Me₃M with Me₂EH. Although cryoscopic molecular weight measurements indicated a trimeric formulation, definitive structural information has been lacking since the original report indicated that these compounds are glassy solids. More recent studies have shown that compounds of empirical composition $R_2MER'_2$ (R,R' = alkyl, aryl) exist as dimers or trimers depending on the steric demands of the substituents. Thus $[(Me_3SiCH_2)_2AsGaPh_2]_2$ [3], $[R_2ME(t-Bu)_2]_2$ $(R = Me, n-Bu; M = Ga, In; E = P, As [4], and [(Me_3SiCH_3)_2InPPh_2]_2$ [5] have been shown to be dimeric by X-ray analysis while mass spectral data indicate that compounds of empirical formula Et_2MPEt_2 (M = Ga, In) are trimeric [6]. A very recent gas phase electron diffraction study of $[Me_2InPMe_2]_3$ [7] is based on the premise that the In_3P_3 ring adopts a chair conformation. This publication prompts us to report details of our recently completed X-ray structure determination of

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Fig. 1. Molecular structure of planar conformer of $[Me_2InAsMe_2]_3$, (1). Typical bond lengths and angles: In(4)-As(4) 2.674(2), In(5)-As(4) 2.673(2), In(5)-As(5) 2.678(2), In(6)-As(5) 2.679(2), In(6)-As(6) 2.673(2), In(4)-As(6) 2.677(2) Å. $C(64)-In(6)-C(63) 124(1), C(52)-As(5)-C(51) 99.2(8)^{\circ}$.

 $[Me_2InAsMe_2]_3$ (1). Although this compound was originally reported to be a glass [2], we have found that slow cooling of concentrated toluene solutions to -20 °C affords colorless crystals of X-ray quality.

Crystal data: $C_{12}H_{36}As_3\ln_3$, M = 749.65, triclinic, space group $P\overline{1}$ (No. 2). a 10.601(3), b 13.921(3), c 17.961(4) Å, α 76.07(2), β 85.38(2), γ 76.48(2)°. U 2500.4 Å³, D_c 1.991 g cm⁻³, Z = 4, λ (Mo- K_{α}) 0.71073 Å, μ (Mo- K_{α}) 66.28 cm⁻¹. A total of 8307 unique reflections was collected on an Enraf--Nonius CAD4 diffractometer at 23 ± 2°C. The structure was solved by direct methods and refined (difference Fourier, full-matrix least-squares) using 3904 reflections with $I > 3\sigma(I)$. The final R and R_w values were 0.041 and 0.052, respectively.

The most interesting structural feature is the presence of two independent molecules in the asymmetric unit. One molecule (Fig. 1) is approximately planar, the deviations from the least squares In_3As_3 plane ranging from 0.097(4) to -0.139(3) Å. The other molecule (Fig. 2) possesses a puckered In_3As_3 ring. The three In atoms and As(3) are virtually coplanar. One As atom (As(2)) lies above this plane by 1.037(4) Å while the other (As(1)) lies below it by 1.252(3) Å. Clearly, this molecule has neither the classic chair nor the boat conformation of cyclohexane. Interestingly, the overall geometry of the In_3As_3 core resembles those of some *d*-block phosphido derivatives such as $[Co(\mu-P(C_6H_{11})_2)(CO)_2]_3$ [8].



Fig. 2. Molecular structure of puckered conformer of $[Me_2InAsMe_2]_3$, (1). Typical bond lengths and angles: In(1)-As(1) 2.657(3), In(2)-As(1) 2.662(2), In(2)-As(2) 2.674(2), In(3)-As(2) 2.661(2), In(3)-As(3) 2.677(2), In(1)-As(3) 2.688(2) Å. C(11)-As(1)-C(12) 99(1), $C(13)-In(1)-C(14) 126(1)^{\circ}$.

Dynamic ¹H NMR data indicate that equivalent In-Me and As-Me environments persist in solution down to -80° C. This suggests either a rapid interconversion of the planar and nonplanar forms of 1 on the NMR timescale or the existence of the planar form in solution.

The foregoing results imply that six-membered rings of alternating heavier group 13 and 15 elements are rather flexible. With a view to further exploration of this idea, the new compound $[Cl_2GaSb(t-Bu)_2]_3$ (2) was synthesized from the reaction of t-Bu₂SbSiMe₃ [9] and GaCl₃ [10]. An X-ray structure determination revealed a boat-type conformation for the Ga₃Sb₃ ring (Fig. 3). Note, however, that the "bow" (Sb(2)) is higher than the "stern" (Ga(2)). The molecule possesses a mirror plane passing through Ga(2) and Sb(2). Thus Sb(2) and Ga(2) lie 0.938 Å and 0.620 Å above the Sb(1)–Sb(1)'–Ga(1)–Ga(1)' plane.

Crystal data: $C_{24}H_{54}Cl_6Ga_3Sb_3$, M = 1129.83, monoclinic, space group $P2_1/m$ (No. 11), a 8.871(1), b 23.630(2), c 11.861(2) Å, β 106.56(1)°, U 2383.2 Å³, D_c 1.574 g cm⁻³, Z = 2, λ (Mo- K_{α}) 0.71073 Å, μ (Mo- K_{α}) 37.08 cm⁻¹. A total of 4290 unique reflections was collected as described above for 1. Solution and refinement of the structure as per 1 but using 3009 reflections with $I > 3\sigma(I)$ afforded final Rand R_w values of 0.0853 and 0.1022 respectively. We attribute these relatively high R values to thermal motion of the t-butyl groups.

There is a paucity of structural data for In-As and Ga-Sb bonds. However, the average In-As bond lengths for 1 (planar form, 2.679(2); puckered form, 2.669(3) Å) are slightly longer than the sum of covalent radii (2.64 Å) or the bond distance in





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Fig. 3. Molecular structure of $[Cl_2GaSb(t-Bu)_2]_3$ (2). Typical bond lengths and angles: Ga(1)-Sb(1) 23.659(2), Ga(1)-Sb(2), 2.662(2), Ga(2)-Sb(1) 2.659(2) Å. Cl(1)-Ga(1)-Cl(2) 108.4(4), C(11)-Sb(1)-C(15) 109.8(9)^{\circ}.

InAs (2.614 Å) [10 *]. The average Ga–Sb bond length for 2 (2.661(2) Å) is the same as the sum of covalent radii (2.66 Å) and similar to the bond distance in GaSb (2.649 Å) [11].

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- 10 (2) M.p. $120-122 \,^{\circ}$ C (dec.), ¹H NMR (C₆D₆, 300 M Hz); δ 1.69 s ppm. ¹³C{¹H} NMR (C₆D₆); 75.47 MHz, δ 33.63 ppm; ⁷¹Ga NMR (C₆D₆, 72.04 MHz, rel. [Ga(H₂O)₆]³⁺ 3(NO₃)⁻); δ 237 ppm, $w_{1/2}$ 1400 Hz. IR (KBr): 2900 vs, br 1497 m, sh, 1396 m, sh, 1369 m, sh, 1366 s,sh, 1263 m, 1210 w, 1148 s,br, 1096 m, br, 1022 s, 938 w,sh, 870 w, 804 m, br, 737 s,sh, 699 m,sh, 504 w,sh, 497 m, 467 m,sh cm⁻¹. Deviations (Å) from the least squares plane through Sb(1), Ga(1), Sb(1)' and Ga(1)' are as follows: Sb(1) 0.079(3), Ga(1) -0.079(3), Sb(1)' -0.079(3), and Ga(1)' -0.079(3).
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